TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

2SK2035

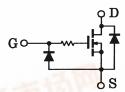
High Speed Switching Applications Analog Switching Applications

- High input impedance.
- Low gate threshold voltage: $V_{th} = 0.5 \sim 1.5 \text{ V}$
- Excellent switching times: $t_{on} = 0.16 \mu s$ (typ.) $t_{off} = 0.15 \,\mu s \,(typ.)$
- Small package
- Enhancement-mode

Marking



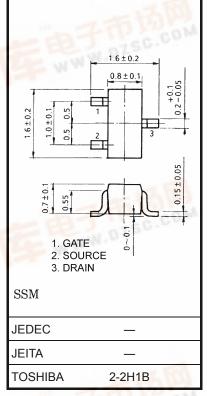
Equivalent Circuit



Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V _{DS}	20	٧
Gate-source voltage	V _{GSS}	10	V
Drain current	I _D	100	mA
Drain power dissipation	P _D	100	mW
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-55~150	°C

Unit: mm



Weight: 2.4 mg (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note: This transistor is electrostatic sensitive device. Please handle with caushon.

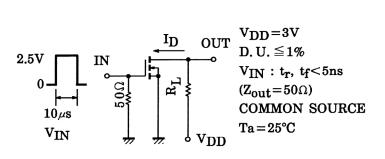


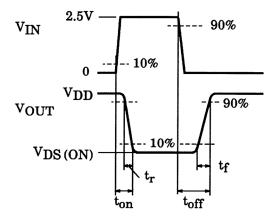


Electrical Characteristics (Ta = 25°C)

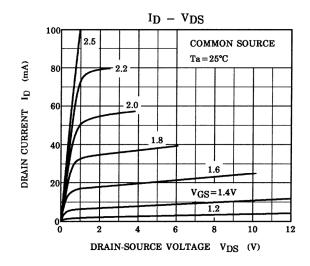
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	V _{GS} = 10 V, V _{DS} = 0	_	_	1	μА
Drain-source breakdown voltage		V (BR) DSS	$I_D = 100 \ \mu A, \ V_{GS} = 0$	20	_		٧
Drain cut-off curre	nt	I _{DSS}	$V_{DS} = 20 \text{ V}, V_{GS} = 0$	_	_	1	μА
Gate threshold vo	Itage	V_{th}	$V_{DS} = 3 \text{ V}, I_D = 0.1 \text{ mA}$	0.5	_	1.5	V
Forward transfer a	admittance	Y _{fs}	$V_{DS} = 3 \text{ V}, I_{D} = 10 \text{ mA}$	25	50	_	mS
Drain-source ON resistance		R _{DS (ON)}	$I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$	_	8	12	Ω
Input capacitance		C _{iss}	$V_{DS} = 3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	8.5	_	pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	3.3	_	pF
Output capacitance		Coss	$V_{DS} = 3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	9.3	_	pF
Switching time	Turn-on time	t _{on}	$V_{DD} = 3 \text{ V}, I_D = 10 \text{ mA}, V_{GS} = 0~2.5 \text{ V}$	_	0.16	_	μS
	Turn-off time	t _{off}	$V_{DD} = 3 \text{ V}, I_D = 10 \text{ mA}, V_{GS} = 0~2.5 \text{ V}$	_	0.15	_	

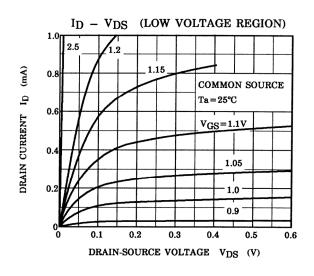
Switching Time Test Circuit

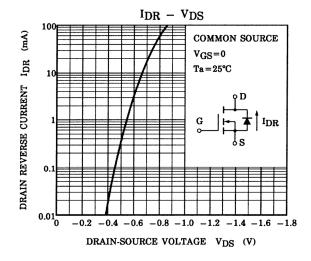


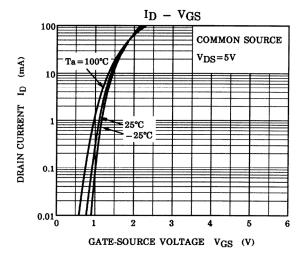


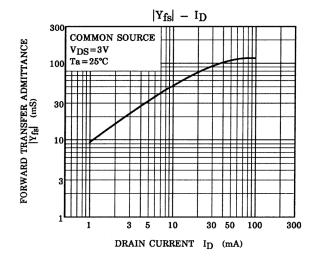
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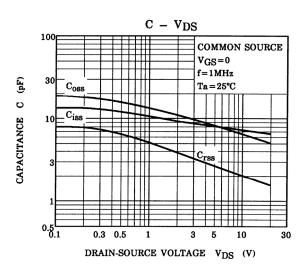


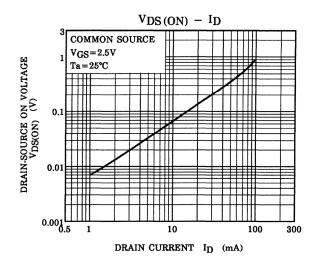


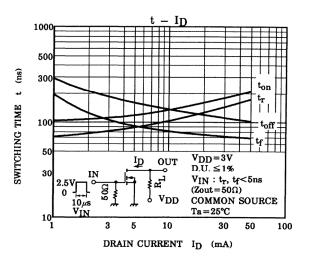


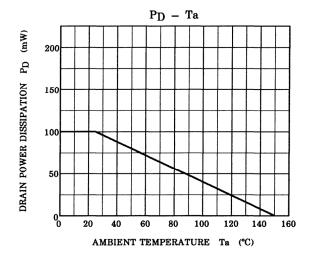












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